



NOTES

1. COATING(S1): BROADBAND DIELECTRIC COATING
2. $R_{\text{avg}} > 99\%$ @ 400 nm–750 nm, $0^\circ - 45^\circ$ AOI
3. CLEAR APERTURE(S1): $> 90\%$ CA
4. SURFACE QUALITY(S1): 20/10(S/D)
5. PARALLELISM(S1, S2): < 3 arcmin
6. CHAMFER: 0.2 mm, 45°
7. BACK SURFACE (S2): FINE GROUND

DRAWING PROJECTION			LBTEK			
	NAME	DATE	BDM1-T1-A-SP			
DRAWN	LZHOU	Aug. /5th/24	BROADBAND DIELECTRIC-COATED PLANO MIRROR $\varnothing 25.4 \text{ mm} \times 1 \text{ mm}$, 400 nm–750 nm			
APPROVAL	WCHENG	Aug. /5th/24	MATERIAL	WEIGHT	SCALE	REV
FOR INFORMATION ONLY NOT FOR MANUFACTURING PURPOSES			UVFS	1.1 g	2:1	A